

# SURFACE MOUNT FAST SWITCHING DIODE

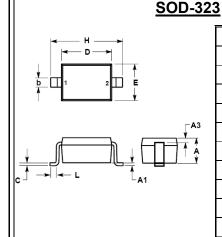
#### REVERSE VOLTAGE – 80 Volts FORWARD CURRENT – 0.1 Ampere

#### **FEATURES**

- · Fast switching speed
- Low reverse leakage current

#### **MECHANICAL DATA**

- Case: SOD-323 Plastic
- Case material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl)
- Moisture sensitivity: Level 1 per J-STD-020D
- Lead free in RoHS 2002/95/EC compliant



SOD-323				
Dim.	Min.	Max.		
Α	0.80	1.00		
A1	0.00	0.10		
А3	0.15 REF			
В	0.25	0.40		
С	0.089	0.177		
D	1.60	1.80		
E	1.15	1.35		
L	0.08			
Н	2.30	2.70		
Dimensions in millimeter				

#### Maximum Ratings & Thermal Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	1SS355	Units
Non-Repetitive Peak Reverse Voltage	$V_{RM}$	90	V
DC Blocking Voltage	V <sub>R</sub>	80	V
Forward Continuous Current	I <sub>FM</sub>	225	mA
Average Rectified Output Current	Io	100	mA
Peak Forward Surge Current @t=1s	I <sub>FSM</sub>	0.5	Α
Junction Temperature	TJ	150	$^{\circ}\mathbb{C}$
Storage Temperature Range	T <sub>STG</sub>	-55~+150	$^{\circ}\!\mathbb{C}$

### **Electrical Characteristics** @ $T_A$ = 25 $^{\circ}$ C unless otherwise specified

Characteristic	Test Condition	Symbol	1SS355	Unit
Maximum Forward Voltage	I <sub>F</sub> = 100mA	V <sub>F</sub>	1.2	V
Maximum DC Reverse Current at Rated DC Blocking Voltage	V <sub>R</sub> = 80V	I <sub>R</sub>	0.1	uA
Typical Diode Capacitance	V <sub>R</sub> =0V,f=1MHz	$C_D$	3	рF
Reverse Recovery time	$V_R$ =6V, $I_R$ = $I_F$ =10mA $R_L$ =100 $\Omega$	trr	4	ns

REV. 3, Jul-2013, KSYR12

#### **RATING AND CHARACTERISTIC CURVES 1SS355**



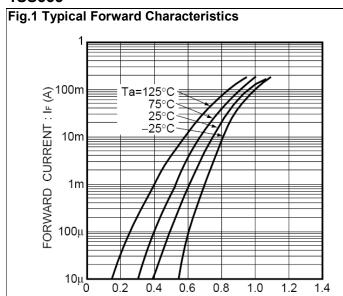
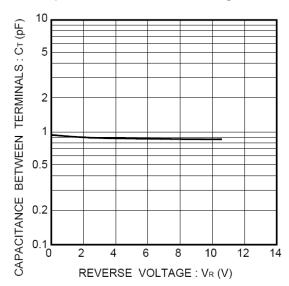


Fig.3 Total Capacitance vs. Reverse Voltage



0.8

0.6

FORWARD VOLTAGE: VF (V)

1.0

1.2

1.4

Fig.5 Surge Current Characteristics

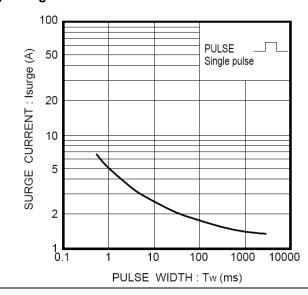


Fig.2 Typical Reverse Characteristics

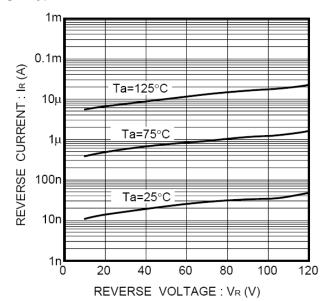


Fig.4 Reverse Recovery Time vs. Forward Current

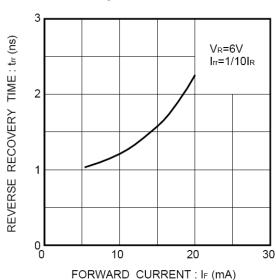
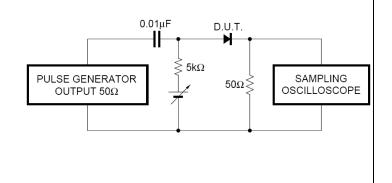


Fig.6 Reverse recovery time (trr) measurement circuit



### Device Marking:



Device P/N	Marking code	Equivalent Circuit Diagram
1SS355	5D	1 0



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## **New Marking Rule Notification**

Range: In order to have well management in process control, the new marking rule is applied to small signal device including Switching Diode, Transistor and Schottky Diode.

Package: SOD-123 / SOD-323 / SOD-523

